

74V1G66

Single bilateral switch

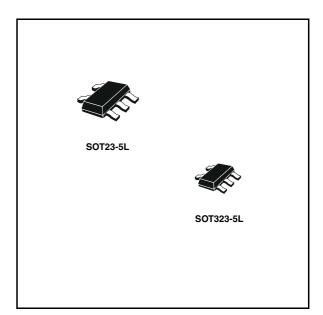
Features

- High speed: t_{PD} = 0.3 ns (typ.) at V_{CC} = 5 V t_{PD} = 0.4 ns (typ.) at V_{CC} = 3.3 V
- Low power dissipation:
 I_{CC} = 1 μA (max.) at T_A = 25 °C
- Low "ON" resistance:
 R_{ON} = 6.5 Ω (typ.) at V_{CC} = 5 V I_{I/O} = 1 mA
 R_{ON} = 8.5 Ω (typ.) at V_{CC} = 3.3 V I_{I/O} = 1 mA
- Sine wave distortion:
 0.04% at V_{CC} = 3.3 V f = 1 kHz
- Wide operating range:
 V_{CC} (opr) = 2 V to 5.5 V
- Improved latch-up immunity

Description

The 74V1G66 is an advanced high-speed CMOS single bilateral switch fabricated in silicon gate C^2 MOS technology. It achieves high speed propagation delay and very low ON resistances while maintaining true CMOS low power consumption. This bilateral switch handles rail to rail analog and digital signals that may vary across the full power supply range (from GND to V_{CC}).

The C input is provided to control the switch and it is compatible with standard CMOS outputs. The switch is ON (port I/O is connected to port O/I) when the C input is held high and OFF (high impedance state exists between the two ports) when C is held low. It can be used in many applications as battery powered systems or test equipments.



The 74V1G66 is available in the commercial and extended temperature range in SOT23-5L and SOT323-5L packages.

All inputs and outputs are equipped with protection circuits against static discharge, giving them ESD immunity and transient excess voltage.

Table 1. Device summary

Order code	Package	Packaging
74V1G66STR	SOT23-5L	Tape and reel
74V1G66CTR	SOT323-5L	Tape and reel

1 Pin connection

Figure 1. Pin connection and IEC logic symbols

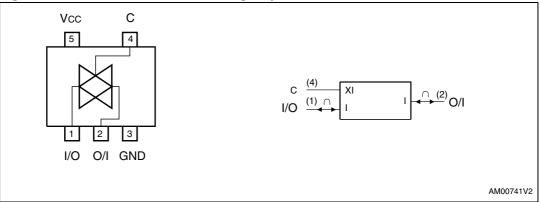


Table 2.Pin description

Pin number	Symbol	Name and function
1	I/O	Independent input/output
2	O/I	Independent output/input
3	GND	Ground (0 V)
4	С	Enable input (active high)
5	V _{CC}	Positive supply voltage

Figure 2. Input equivalent circuit

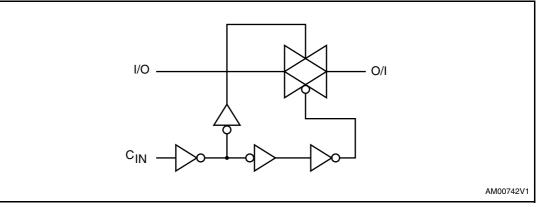


Table 3.Truth table

Control	Switch function
Н	ON
L	OFF ⁽¹⁾

1. High impedance state.



2 Maximum rating

Stressing the device above the rating listed in the "Absolute Maximum Ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	-0.5 to +7.0	V
VI	DC input voltage	-0.5 to V _{CC} + 0.5	V
V _{IC}	DC control input voltage	-0.5 to +7.0	V
Vo	DC Output voltage	-0.5 to V _{CC} + 0.5	V
Ι _{ΙΚ}	DC input diode current	±20	mA
I _{IK}	DC control input diode current	- 20	mA
Ι _{ΟΚ}	DC output diode current	±20	mA
Ι _Ο	DC output current	±50	mA
I _{CC} or I _{GND}	DC V _{CC} or ground current	±50	mA
T _{stg}	Storage temperature	-65 to +150	°C
ΤL	Lead temperature (10 sec)	300	°C

Table 4. Absolute maximum ratings

Table 5. Recommended operating conditions

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	2 to 5.5	V
VI	Input voltage	0 to V _{CC}	V
V _{IC}	Control input voltage	0 to 5.5	V
V _O	Output voltage	0 to V _{CC}	V
T _{op}	Operating temperature	-55 to 125	°C
dt/dv	Input rise and fall time ⁽¹⁾ $V_{CC} = 5.0 V$	0 to 20	ns/V

1. V_{IN} from 30% to 70% of V_{CC} on control pin.



Symbol Par		Tes	st condition	Value							
	Parameter	V _{CC}		г	T _A = 25°C		-40 to 85°C		-55 to 125°C		Unit
		(V)		Min	Тур	Мах	Min	Max	Min	Max	
	High level input	2.0		1.5			1.5		1.5		
V _{IH}	voltage	2.7 to 5.5		0.7V _C c			0.7V CC		0.7V CC		V
		2.0				0.5		0.5		0.5	
V_{IL}	Low level input voltage	2.7 to 5.5				0.3V _C c		0.3V cc		0.3V cc	V
		3.3 ⁽¹⁾	$V_{IC} = V_{IH}$		12.5	21		23		27	
R _{ON}	ON resistance	5.0 ⁽²⁾	V _{I/O} = V _{CC} to GND I _{I/O} ≤1mA		7.5	10		12		14	Ω
		3.3 ⁽¹⁾	$V_{IC} = V_{IH}$		8.5	11.5		12.5		15	
R _{ON}	ON resistance	5.0 ⁽²⁾	$V_{I/O} = V_{CC} \text{ or}$ GND $I_{I/O} \le 1 \text{mA}$		6.5	8.5		10		12	Ω
I _{OFF}	Input/output leakage current (switch OFF)	5.5	$V_{OS} = V_{CC} \text{ to}$ GND $V_{IS} = V_{CC} \text{ to}$ GND $V_{IC} = V_{IL}$			±0.1		±1		±5	μΑ
Ι _{ΙΖ}	Switch input leakage current (switch ON, output open)	5.5	$V_{OS} = V_{CC}$ to GND $V_{IC} = V_{IH}$			±0.1		±1		±5	μΑ
I _{IN}	Control input leakage current	0 to 5.5	V _{IC} = 5.5V or GND			±0.1		±1.0		±1.0	μA
I _{CC}	Quiescent supply current	5.5	V _I = V _{CC} or GND			1		10		20	μA

Table 6.DC specifications

1. Voltage range is 3.3 V \pm 0.3 V.

2. Voltage range is $5 V \pm 0.5 V$.



				,		-1 -	,				
		т	est condition	Value							
Symbol	nbol Parameter	V _{CC}		T _A = 25°C		-40 to 85°C		-55 to 125°C		Unit	
		(V)		Min	Тур	Max	Min	Max	Min	Max	
+	Delay time	3.3 ⁽¹⁾			0.4	0.8		1.2		2.4	ns
t _{PD}	Delay line	5.0 ⁽²⁾	$t_r = t_f = 6 \text{ ns}$		0.3	0.6		1.0		2.0	115
t _{PLZ}	Output disable	3.3 ⁽¹⁾	R ₁ = 500 Ω		5.0	7.5		9.0		10.0	ns
t _{PHZ}	time	5.0 ⁽²⁾	112 - 300 32		5.0	7.5		9.0		10.0	115
t _{PZL}	Output enable time	3.3 ⁽¹⁾	R _I = 1 ΚΩ		2.5	4.0		5.0		7.0	ns
t _{PZH}		5.0 ⁽²⁾	η ₁ = 1 132		2.0	4.0		5.0		7.0	115

Table 7. AC electrical characteristics ($C_L = 50 \text{ pF}$, input $t_r = t_f = 3 \text{ ns}$)

1. Voltage range is 3.3 V \pm 0.3 V.

2. Voltage range is 5 V \pm 0.5 V.

Table 8.Capacitive characteristics

		Т	est condition	Value							
Symbol	Parameter	V _{CC}		Т	_A = 25°	С	-40 to	85°C		i to 5°C	Unit
		(V)		Min	Тур	Max	Min	Max	Min	Max	
C _{IN}	Input capacitance				3	10		10		10	pF
C _{I/O}	Output capacitance				10						pF
<u> </u>	Power dissipation	3.3			2.5						pF
C _{PD}	capacitance ⁽¹⁾	5.0			3						μL

1. C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to the test circuit). Average operating current can be obtained by the following equation. $I_{CC}(opr) = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$.



			Test condition			
Symbol	Parameter	V _{CC} (V)	V _{IN} (V _p . _p)		Тур	Unit
	Sine wave	3.3 ⁽¹⁾	2.75	f _{IN} = 1 KHz R _I = 10 KΩ C _I = 50 pF	0.04	%
	distortion (THD)	5.0 ⁽²⁾	4	$I_{N} = 1 K_{12} H_{L} = 10 K_{22} C_{L} = 30 \mu F$	0.04	/0
	Frequency	3.3 ⁽¹⁾		f_{IN} voltage to obtain 0 dBm at V _{OS} .	150	
† _{MAX}	response (switch ON)	5.0 ⁽²⁾		crease f _{IN} Frequency until dB meter reads -3dB $_{\rm L}$ = 50 Ω C $_{\rm L}$ = 10 pF		MHz
	Feed through	3.3 ⁽¹⁾	V _{IN} is	centered at $V_{CC}/2$	-60	
	attenuation (switch OFF)	5.0 ⁽²⁾		f_{IN} Voltage to obtained 0dBm at V _{IS} 00 Ω , C _L = 50 pF, f_{IN} = 1KHz sine wave	-60	dB
	Crosstalk	3.3 ⁽¹⁾	$B_1 = 6$	00 Ω C ₁ = 50 pF, f_{IN} = 1 KHz square wave	60	
	(control input to signal output)	5.0 ⁽²⁾			60	mV

Table 9.Analog switch characteristics (GND = 0 V; $T_A = 25^{\circ}C$)

1. Voltage range is 3.3 V \pm 0.3 V

2. Voltage range is 5.0 V ± 0.5 V



Enable and disable timing

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3 Switching characteristics test circuit

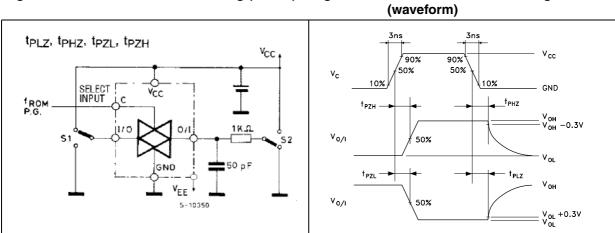
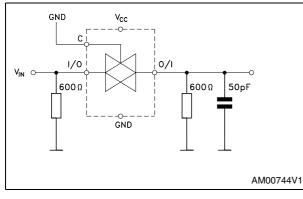
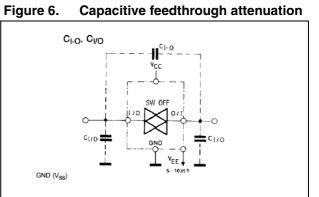


Figure 5. Resistive feedthrough attenuation





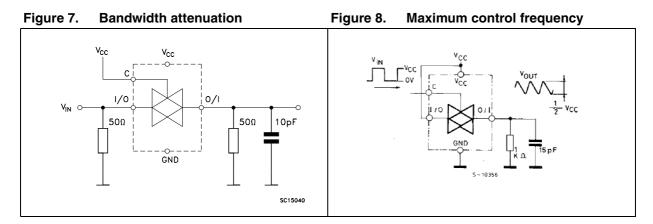
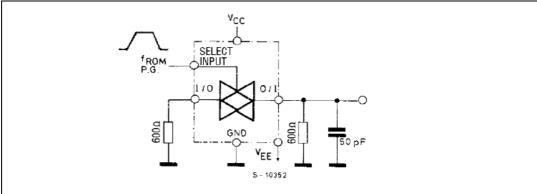


Figure 3. Enable and disable timing (circuit) Figure 4.

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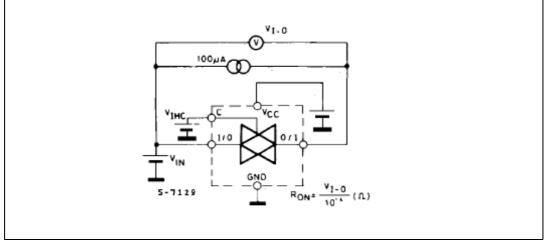
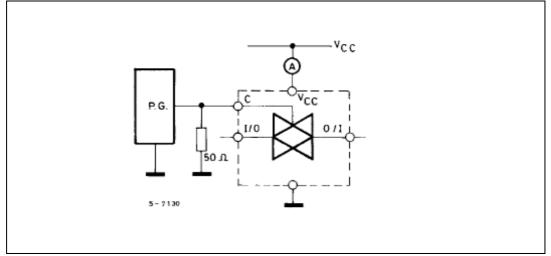


Figure 11. I_{CC} (opr)



4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.



DIM.

A A1 A2 b C D

Е

е

Н

2.80

1.50

2.60

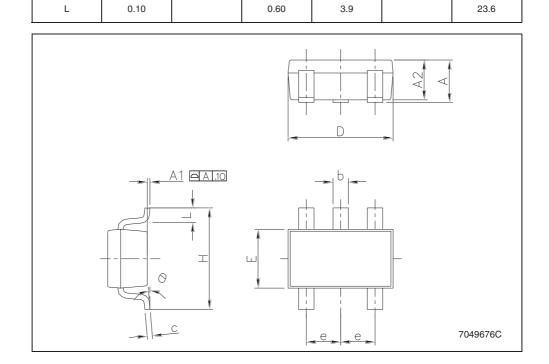
SOT23-5L MECHANICAL DATA								
mm. mils								
MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.			
0.90		1.45	35.4		57.1			
0.00		0.10	0.0		3.9			
0.90		1.30	35.4		51.2			
0.35		0.50	13.7		19.7			
0.09		0.20	3.5		7.8			
					1			

110.2

59.0

102.3

37.4



3.00

1.75

3.00

0.95

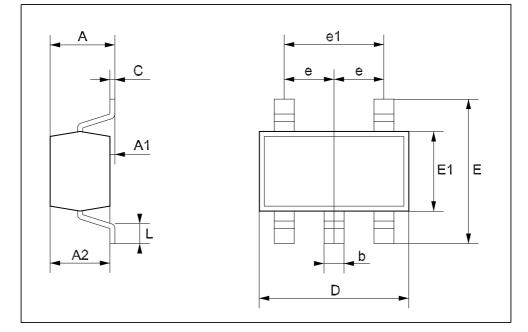
118.1

68.8

118.1



	SOT323-5L MECHANICAL DATA								
DIM		mm.			mils				
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.			
А	0.80		1.10	31.5		43.3			
A1	0.00		0.10	0.0		3.9			
A2	0.80		1.00	31.5		39.4			
b	0.15		0.30	5.9		11.8			
С	0.10		0.18	3.9		7.1			
D	1.80		2.20	70.9		86.6			
E	1.80		2.40	70.9		94.5			
E1	1.15		1.35	45.3		53.1			
е		0.65			25.6				
e1		1.3			51.2				
L	0.10		0.30	3.9	1	11.8			





DIM.

A C D N T

Ao

Во

Ko

Po

3.13

3.07

1.27

3.9

3.23

3.17

1.37

4.0

Tape & Reel SOT23-xL MECHANICAL DATA								
mm. inch								
MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.			
		180			7.086			
12.8	13.0	13.2	0.504	0.512	0.519			
20.2			0.795					
60			2.362					
		14.4			0.567			

0.123

0.120

0.050

0.153

0.127

0.124

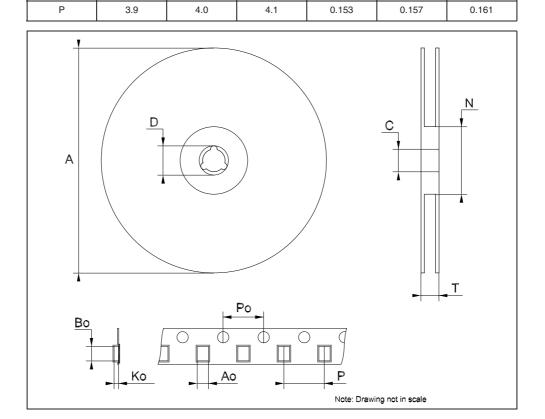
0.054

0.157

0.131

0.128

0.161



3.33

3.27

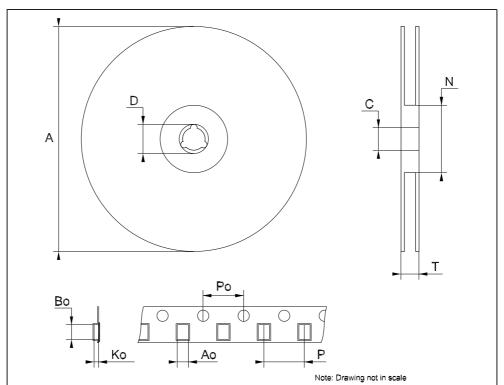
1.47

4.1





	Tape & Reel SOT323-xL MECHANICAL DATA							
DIM.	mm.			inch				
	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.		
A	175	180	185	6.889	7.086	7.283		
С	12.8	13	13.2	0.504	0.512	0.519		
D	20.2			0.795				
N	59.5	60	60.5		2.362			
Т			14.4			0.567		
Ao		2.25			0.088			
Во		2.7			0.106			
Ko		1.2			0.047			
Po	3.9	4	4.1	0.153	0.157	0.161		
Р	3.8	4	4.2	0.149	0.157	0.165		





5 Revision history

Table 10. Document revision history

Date	Revision	Changes
01-Apr-2004	7	Updated data reel information.
28-Oct-2008 8		Document reformatted to improve readability. Updated <i>Table 6: DC specifications on page 4</i> .



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